

BRMJD41CQ

Rev.A Oct.-2023

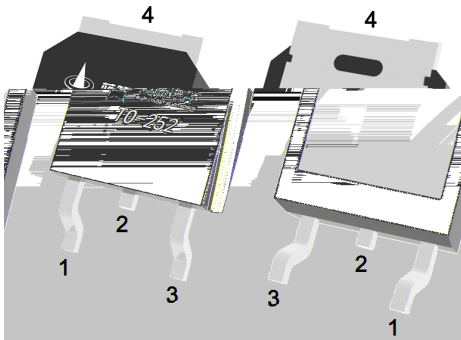
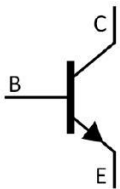
TO-252 NPN

Silicon NPN transistor in a TO-252 Plastic Package.

BRMJD42CQ AEC-Q101

Complement to BRMJD42CQ, Qualified to AEC-Q101 Standards for High Reliability, HF Product.

Medium power linear switching applications, Meet the stringent requirements of automotive applications.



PIN1 Base

PIN 2,4 Collector

PIN 3 Emitter

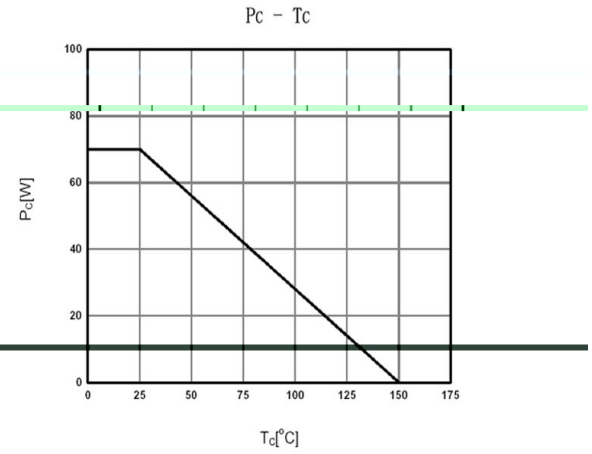
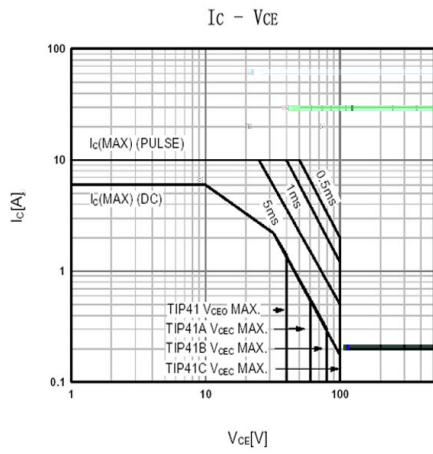
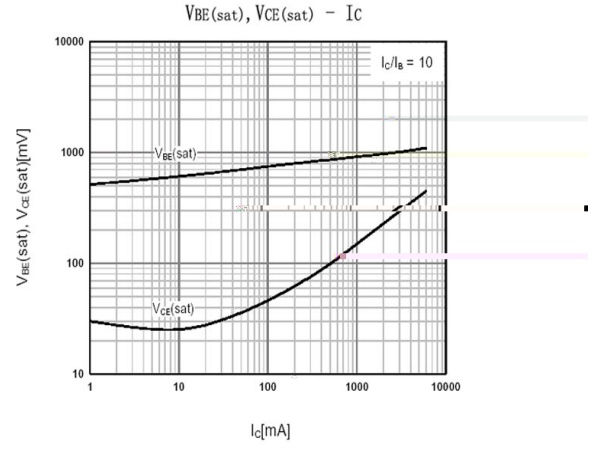
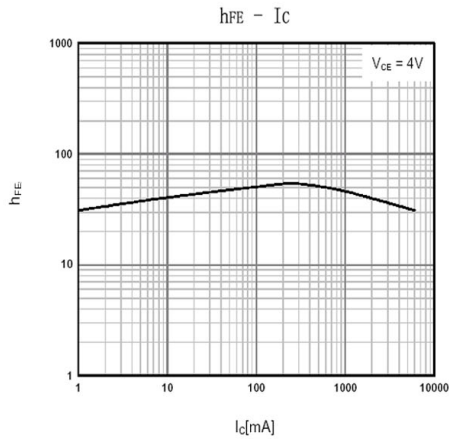
/ Absolute Maximum Ratings($T_a=25$)

Parameter	Symbol	Rating	Unit
Collector to Base Voltage	V_{CBO}	100	V
Collector to Emitter Voltage	V_{CEO}	100	V
Emitter to Base Voltage	V_{EBO}	5.0	V
Collector Current - Continuous	I_C	6.0	A
Base Current - Continuous	I_B	2.0	A
Collector Power Dissipation	P_D	1.75	W
Collector Power Dissipation	$P_D(T_C=25)$	20	W
Junction Temperature	T_j	150	
Storage Temperature Range	T_{stg}	-55 150	

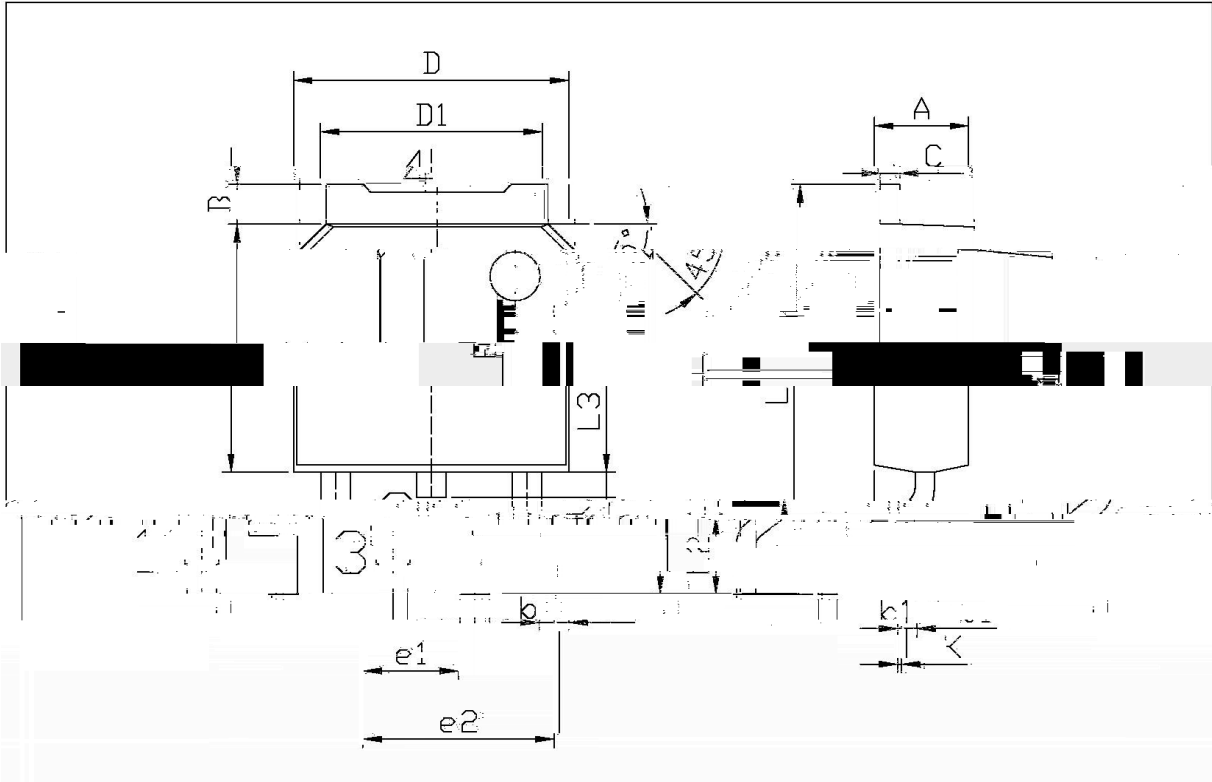
/ Electrical Characteristics($T_a=25$)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Collector to Emitter Breakdown Voltage	V_{CEO}	$I_C=30mA$ $I_B=0$	100			V
Collector Cut-Off Current	I_{CEO}	$V_{CE}=60V$ $I_B=0$			50	μA
Collector Cut-Off Current	I_{CES}	$V_{CE}=100V$ $V_{BE}=0$			10	μA
Emitter Cut-Off Current	I_{EBO}	$V_{BE}=5.0V$ $I_C=0$			0.5	mA
DC Current Gain	$h_{FE(1)}$	$V_{CE}=4.0V$ $I_C=3.0A$	15		75	
	$h_{FE(2)}$	$V_{CE}=4.0V$ $I_C=0.3A$	30			
Collector to Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=6.0A$ $I_B=600mA$			1.5	V
Base to Emitter On Voltage	$V_{BE(on)}$	$V_{CE}=6.0V$ $I_C=4.0A$			2.0	V
Current- Gain Bandwidth Product	f_T	$V_{CE}=10V$ $I_C=500mA$	3			MHz

/ Electrical Characteristic Curve



/ Package Dimensions



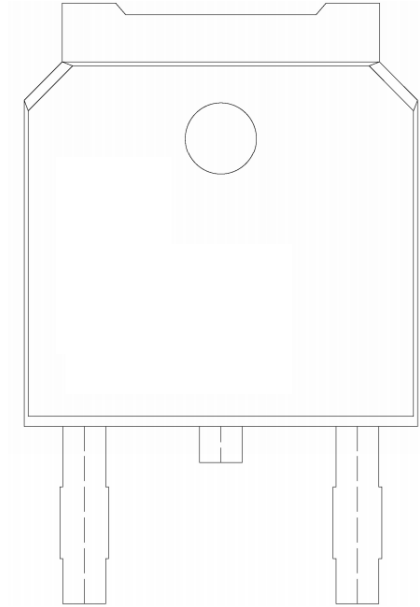
单位: mm

Symbol	Dimensions In Millimeters		Symbol	Dimensions In Millimeters	
	Min.	Max.		Min.	Max.
A	2.20	2.40	E	5.90	6.25
B	0.95	1.25	e1	2.20	2.34
C	0.70	0.90	e2	4.30	4.73
D	0.45	0.55	b1	9.85	10.35
D1	0.55	0.70	L3	0.60	0.90
L3	6.45	6.75	k	0.50	0.60
L3	0.50	0.55			

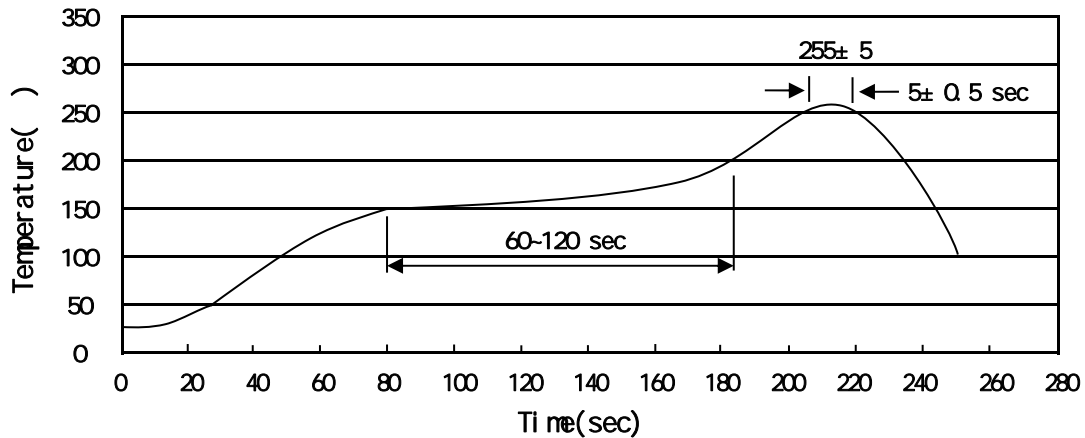
TO-252

41CQ(2.26)

3mn6.1Tarking



() / Temperature Profile for IR Reflow Soldering(Pb-Free)



Note:

- 1 150 200 60 120sec; 1.Preheating:150~200 , Time:60~120sec.
- 2 255±5 5±0.5sec; 2.Peak Temp.:255±5 , Duration:5±0.5sec.
- 3 2 10 /sec. 3. Cooling Speed: 2~10 /sec.

/ Resistance to Soldering Heat Test Conditions

260±5 10±1 sec. Temp.:260±5 Time:10±1 sec

/ Packaging SPEC.

/ REEL

Package Type	Units					Dimension (unit mm ³)		
	Units/Reel	Reels/Inner Box	Units/Inner Box	Inner Boxes/Outer Box	Units/Outer Box	Reel	Inner Box	Outer Box
TO-252	2,500	2	5,000	6	30,000	13 x16	360x360x50	380x335x366

/ TUBE

Package Type	Units					Dimension (unit mm ³)		
	Units/Tube	Tubes/Inner Box	Units/Inner Box	Inner Boxes/Outer Box	Units/Outer Box	Tube	Inner Box	Outer Box
TO-251/252	75	48	3,600	5	18,000	526x20.5x5.25	555x164x50	575x290x180

/ Notices